Low-Voltage CMOS Hex Inverter

With 5 V–Tolerant Inputs

The MC74LCX04 is a high performance hex inverter operating from a 2.0 to 5.5 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX04 inputs to be safely driven from 5 V devices if V_{CC} is less than 5.0 V.

Current drive capability is 24 mA at the outputs.

Features

- Designed for 2.0 V to 5.5 V V_{CC} Operation
- 5 V Tolerant Inputs Interface Capability With 5 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10 µA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V; Machine Model >200 V
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

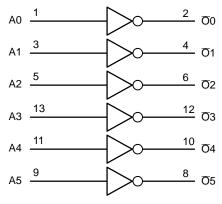


Figure 1. Logic Diagram



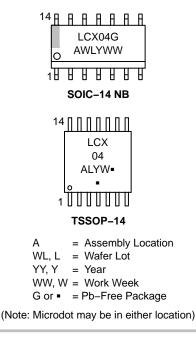
ON Semiconductor®

http://onsemi.com



PIN ASSIGNMENT <u>0</u>5 04 V_{CC} A3 <u>0</u>3 A4 A5 14 13 12 11 10 9 8 1 2 3 4 5 6 7 <u>0</u>0 A2 02 GND A0 A1 <u>0</u>1 14-Lead (Top View)

MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

PIN NAMES

Pins	Function
An	Data Inputs
Ōn	Outputs

TRUTH TABLE

An	Ōn
L	H
H	L

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \leq V_l \leq +7.0$		V
Vo	DC Output Voltage	$-0.5 \leq V_O \leq V_{CC} + 0.5$	Output in HIGH or LOW State (Note 1)	V
Ι _{ΙΚ}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
Ι _Ο	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C
MSL	Moisture Sensitivity		Level 1	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Pa	rameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	Operating Data Retention Only	2.0 1.5	2.5, 3.3 2.5, 3.3	5.5 5.5	V
VI	Input Voltage		0		5.5	V
V _O	Output Voltage	(HIGH or LOW State) (3–State)	0		V _{CC}	V
I _{OH}	HIGH Level Output Current	$V_{CC} = 3.0 V - 3.6 V$ $V_{CC} = 2.7 V - 3.0 V$ $V_{CC} = 2.3 V - 2.7 V$			-24 -12 -8	mA
I _{OL}	LOW Level Output Current	$V_{CC} = 3.0 V - 3.6 V$ $V_{CC} = 2.7 V - 3.0 V$ $V_{CC} = 2.3 V - 2.7 V$			+24 +12 +8	mA
T _A	Operating Free–Air Temperature		-55		+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate	, V _{IN} from 0.8 V to 2.0 V, V _{CC} = 3.0 V	0		10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

			T _A = −55°C	to +125°C	
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2)	$2.3 \text{ V} \leq \text{V}_{\text{CC}} \leq 2.7 \text{ V}$	1.7		V
		$2.7 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V}$	2.0		
VIL	LOW Level Input Voltage (Note 2)	$2.3 \text{ V} \leq \text{V}_{\text{CC}} \leq 2.7 \text{ V}$		0.7	V
		$2.7 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V}$		0.8	
V _{OH}	HIGH Level Output Voltage	$2.3 \text{ V} \leq \text{V}_{CC} \leq 3.6 \text{ V}; \text{ I}_{OH} = -100 \mu\text{A}$	V _{CC} – 0.2		V
		V _{CC} = 2.3 V; I _{OH} = -8 mA	1.8		
		$V_{CC} = 2.7 \text{ V}; I_{OH} = -12 \text{ mA}$	2.2		
		$V_{CC} = 3.0 \text{ V}; \text{ I}_{OH} = -18 \text{ mA}$	2.4		
		$V_{CC} = 3.0 \text{ V}; \text{ I}_{OH} = -24 \text{ mA}$	2.2		
V _{OL}	LOW Level Output Voltage	$2.3 \text{ V} \leq \text{V}_{CC} \leq 3.6 \text{ V}; \text{ I}_{OL} = 100 \mu\text{A}$		0.2	V
		V _{CC} = 2.3 V; I _{OL} = 8 mA		0.6	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 16 mA		0.4	
		$V_{CC} = 3.0 \text{ V}; \text{ I}_{OL} = 24 \text{ mA}$		0.55	
I _{OFF}	Power Off Leakage Current	V_{CC} = 0, V_{IN} = 5.5 V or V_{OUT} = 5.5 V		10	μΑ
I _{IN}	Input Leakage Current	V_{CC} = 3.6 V, V_{IN} = 5.5 V or GND		±5	μΑ
I _{CC}	Quiescent Supply Current	V_{CC} = 3.6 V, V_{IN} = 5.5 V or GND		10	μΑ
ΔI_{CC}	Increase in I _{CC} per Input	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; \text{ V}_{IH} = \text{V}_{CC} - 0.6 \text{ V}$		500	μΑ

2. These values of V_{I} are used to test DC electrical characteristics only.

AC CHARACTERISTICS (t_R = t_F = 2.5 ns; R_L = 500 $\Omega)$

			Limits						
					$T_A = -55^{\circ}C$	to +125°C			
			V _{CC} = 3.3	V \pm 0.3 V	V _{CC} =	: 2.7 V	V _{CC} = 2.5	$V \pm 0.2 V$	
			C _L =	50 pF	C _L =	50 pF	C _L =	30 pF	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay Time	1	1.5	5.2	1.5	6.0	1.5	6.2	ns
t _{PHL}	Input to Output		1.5	5.2	1.5	6.0	1.5	6.2	
t _{OSHL}	Output-to-Output Skew			1.0					ns
t _{OSLH}	(Note 3)			1.0					

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

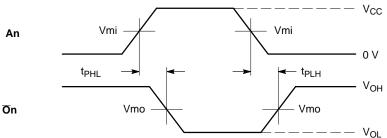
DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage	V_{CC} = 3.3 V, C_{L} = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V		0.8		V
	(Note 4)	V_{CC} = 2.5 V, C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V		0.6		V
V _{OLV}	Dynamic LOW Valley Voltage	V_{CC} = 3.3 V, C_{L} = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V		-0.8		V
	(Note 4)	V_{CC} = 2.5 V, C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V		-0.6		V

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

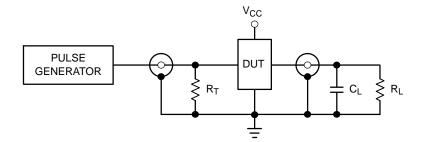
Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	25	pF



WAVEFORM 1 – PROPAGATION DELAYS $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1 MHz; $t_W = 500$ ns

	v _{cc}			
Symbol	$3.3 \text{ V} \pm 0.3 \text{ V}$	2.7 V	$2.5 \text{ V} \pm 0.2 \text{ V}$	
Vmi	1.5 V	1.5 V	V _{CC} /2	
Vmo	1.5 V	1.5 V	V _{CC} /2	

Figure 2. AC Waveforms



 $\begin{array}{l} C_L = 50 \ \text{pF} \ \text{at} \ V_{CC} = \ 3.3 \pm 0.3 \ \text{V} \ \text{or equivalent (includes jig and probe capacitance)} \\ C_L = \ 30 \ \text{pF} \ \text{at} \ V_{CC} = \ 2.5 \pm 0.2 \ \text{V} \ \text{or equivalent (includes jig and probe capacitance)} \\ R_L = \ R_1 = 500 \ \Omega \ \text{or equivalent} \\ R_T = \ Z_{OUT} \ \text{of pulse generator (typically 50 } \Omega) \end{array}$

Figure 3. Test Circuit

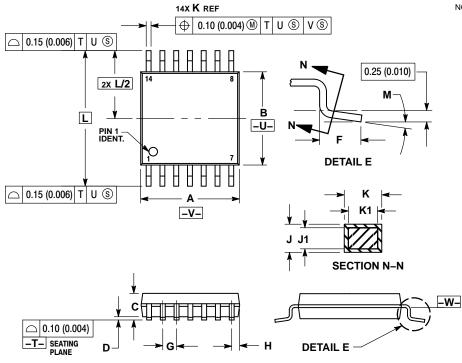
ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LCX04DG	SOIC-14 NB (Pb-Free)	55 Units / Rail
MC74LCX04DR2G	SOIC-14 NB (Pb-Free)	2500 Tape & Reel
MC74LCX04DTG	TSSOP-14 (Pb-Free)	96 Units / Rail
MC74LCX04DTR2G	TSSOP-14 (Pb-Free)	2500 Tape & Reel
NLV74LCX04DTR2G*	TSSOP-14 (Pb-Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable

PACKAGE DIMENSIONS

TSSOP-14 CASE 948G **ISSUE B**

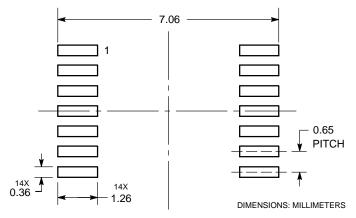


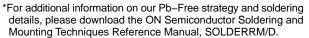
NOTES: 1. DIMENSIONING AND TOLERANCING PER

DIRENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: MILLIMETER.
DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
TERERENCE ONLY.
DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.
MILLIMETERS INCHES

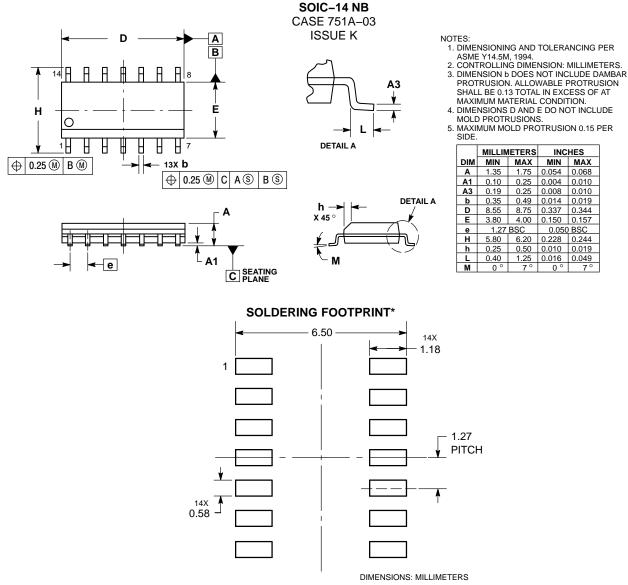
	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
н	0.50	0.60	0.020	0.024	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
κ	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40 BSC		0.252 BSC		
М	0 °	° 8	0 °	8 °	

SOLDERING FOOTPRINT*





PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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